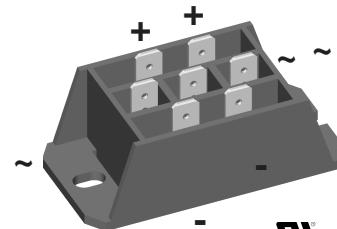
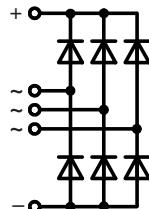


Three Phase Rectifier Bridge

I_{dAV} = 72 A
V_{RRM} = 1200-1800 V

V _{RSM} V	V _{RRM} V	Type
1300	1200	VUO 60-12NO3
1500	1400	VUO 60-14NO3
1700	1600	VUO 60-16NO3
1900	1800	VUO 60-18NO3*

* delivery time on request



E72873

Symbol	Conditions	Maximum Ratings		
I _{dAV} ①	T _c = 85°C, module	72	A	
I _{dAVM} ①	module	75	A	
I _{FSM}	T _{VJ} = 45°C; V _R = 0	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	600 650	A A
	T _{VJ} = T _{VJM} V _R = 0	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	540 600	A A
I ² t	T _{VJ} = 45°C V _R = 0	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	1800 1770	A ² s A ² s
	T _{VJ} = T _{VJM} V _R = 0	t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine	1460 1510	A ² s A ² s
T _{VJ}		-40...+125	°C	
T _{VJM}		125	°C	
T _{stg}		-40...+125	°C	
V _{ISOL}	50/60 Hz, RMS I _{ISOL} ≤ 1 mA	t = 1 min t = 1 s	3000 3600	V~ V~
M _d	Mounting torque	(M5) (10-32 UNF)	2-2.5 18-22	Nm lb.in.
Weight	typ.		50	g

Symbol	Conditions	Characteristic Values		
I _R	V _R = V _{RRM} ; V _R = V _{RRM} ;	T _{VJ} = 25°C T _{VJ} = T _{VJM}	0.3 5	mA mA
V _F	I _F = 150 A;	T _{VJ} = 25°C	1.9	V
V _{To}	For power-loss calculations only		0.8	V
r _T			6.5	mΩ
R _{thJC}	per diode, DC current		1.2	K/W
	per module		0.2	K/W
R _{thJH}	per diode, DC current		1.6	K/W
	per module		0.27	K/W
d _S	Creep distance on surface		10	mm
d _A	Strike distance in air		9.4	mm
a	Max. allowable acceleration		50	m/s ²

Data according to IEC 60747 and refer to a single diode unless otherwise stated.
 ① for resistive load at bridge output.

IXYS reserves the right to change limits, test conditions and dimensions.

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Features

- Package with DCB ceramic base plate
- Isolation voltage 3600 V~
- Planar passivated chips
- Blocking voltage up to 1800 V
- low forward voltage drop
- 1/4" fast-on terminals
- UL registered E 72873

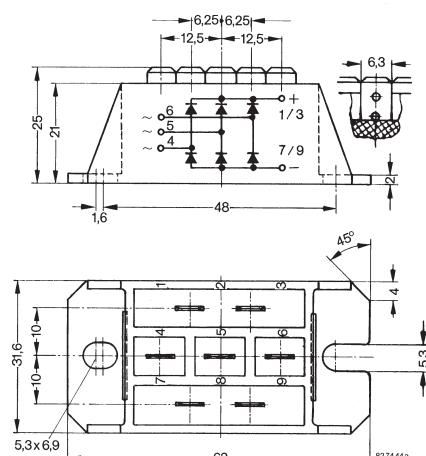
Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Rectifier for DC motors field current

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling

Dimensions in mm (1 mm = 0.0394")



Use output terminals in parallel connection!

20080527a

1 - 2

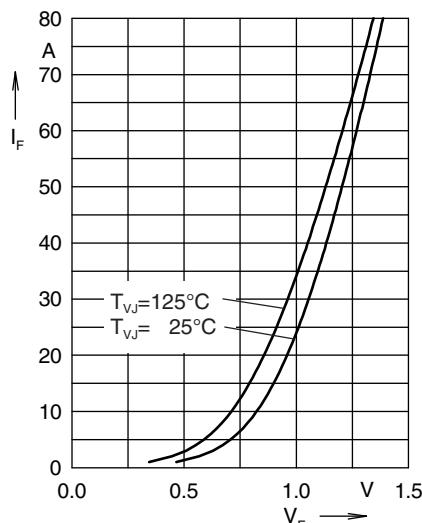


Fig. 4 Forward current versus voltage drop per diode

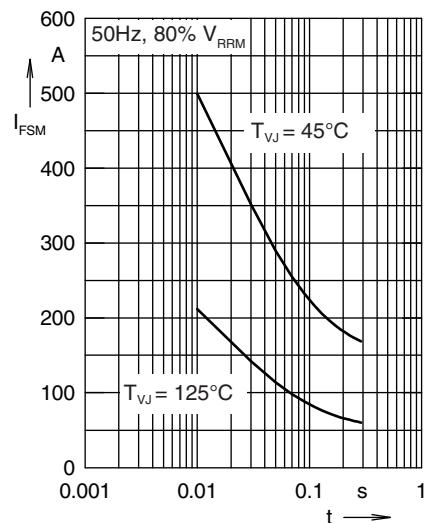


Fig. 5 Surge overload current

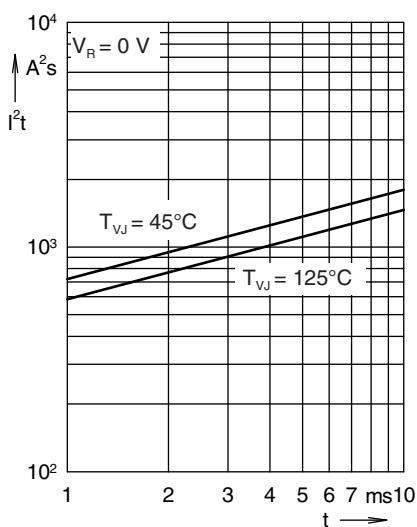
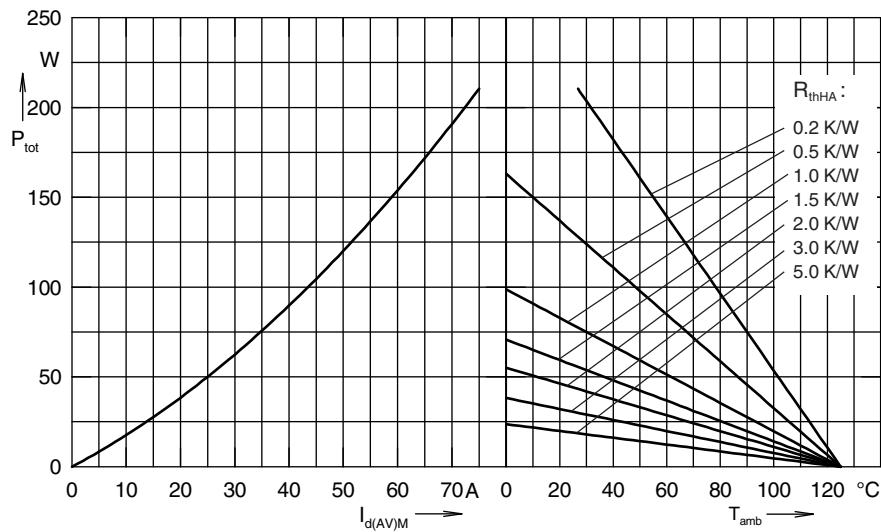
Fig. 6 I^2t versus time per diode

Fig. 7 Power dissipation vs. direct output current and ambient temperature

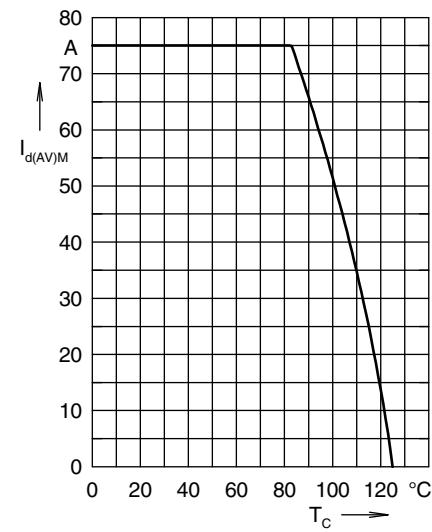


Fig. 8 Max. forward current vs. case temperature

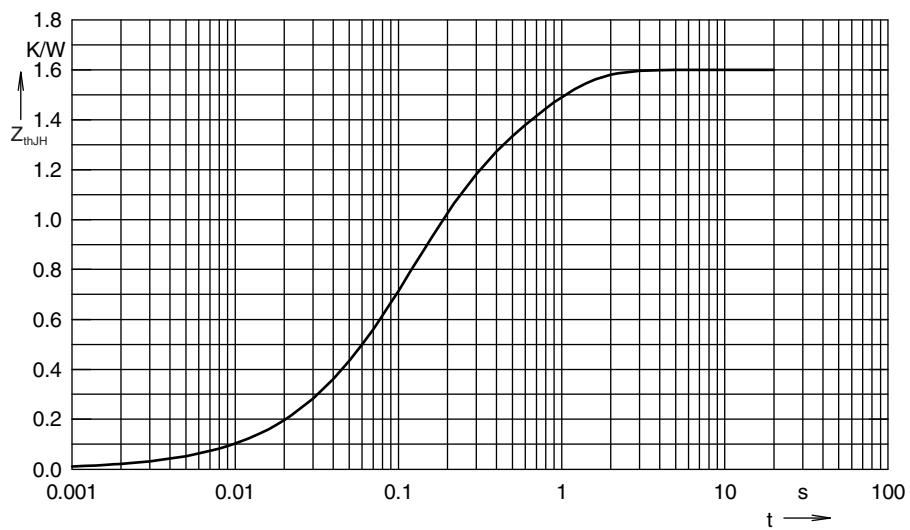


Fig. 9 Transient thermal impedance junction to heatsink

Constants for Z_{thJH} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.883	0.102
2	0.098	0.103
3	0.202	0.492
4	0.417	0.62